

# Charger Design with iW1690 (EBC101)

## General Design Specification :

1. AC Input Range 90-264Vac
2. DC Output 5V, 550mA~650mA (CC)
3. No-load Standby Power Consumption <0.15W@230Vac
4. Max Ripple 150mV<sub>P-P</sub>
5. No Y-CAP design.

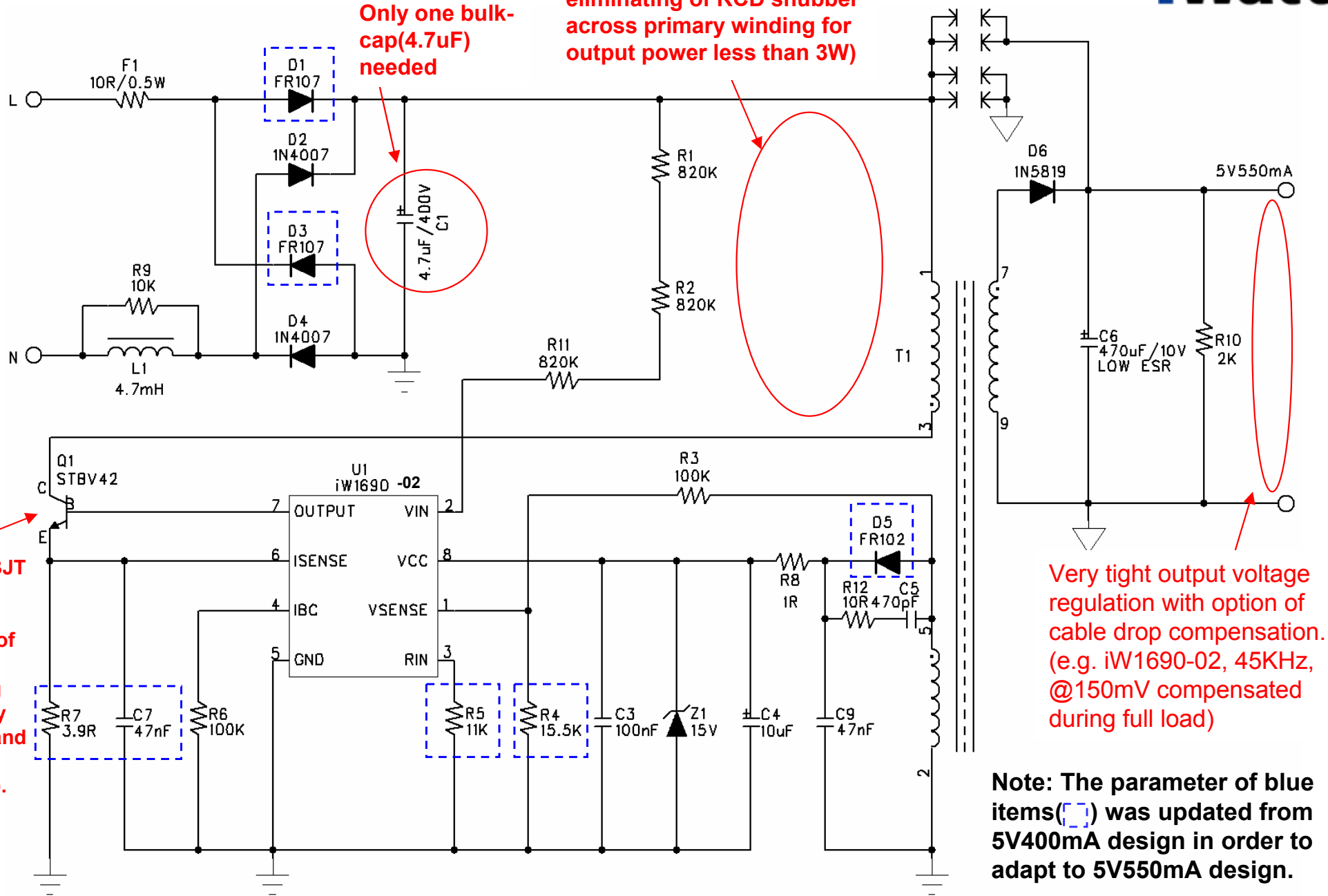
# 1. Specification

Description		Symbol	Min	Typ	Max	Units	Comment
<b>Input</b>							
Voltage		$V_{IN}$	90		264	V <sub>AC</sub>	2 Wire
Frequency		$f_{LINE}$	47	50/60	63	Hz	
No-load Input Power (264V <sub>AC</sub> )					0.15	W	
<b>Output</b>							
Const Voltage	Output Voltage	$V_{OUT\_CV}$	4.75	5	5.25	V	Measured at the end of Cable
	Output Current	$I_{OUT\_CV}$	0		0.8	A	
Const Current	Output Voltage	$V_{OUT\_CC}$	< 2.0	Depending on battery voltage		V	Min V <sub>OUT</sub> is dependence of V <sub>CC</sub> supply voltage
	Output Current	$I_{OUT\_CC}$	0.55		0.65	A	
Output Ripple Voltage		$V_{RIPPLE}$			150	mV <sub>P-P</sub>	Measured at the End of DC Output cable I <sub>OUT</sub> =0.55A @T <sub>A</sub> = 25 °C 20 MHz Bandwidth
<b>Total Output Power</b>							
Continuous Output Power		$P_{OUT}$			2.75	W	
Over Current Protection		$I_{OUT\_MAX}$			0.65	A	Auto-restart
Efficiency		$\eta$	64			%	Measured at end of PCB, V <sub>IN</sub> = 90V <sub>AC</sub> I <sub>OUT</sub> = 550mA. (T <sub>A</sub> = 25 °C)
<b>Environmental</b>							
Conducted EMI			Meets CISPR22B / EN55022B				
Safety			Designed to meet IEC950, UL1950 Class II				
Ambient Temperature		$T_{AMB}$	0		40	° C	Free convection, sea level

## 2. Schematic

Used of BJT allow eliminating of RCD snubber across primary winding for output power less than 3W)

Only one bulk-cap(4.7uF) needed



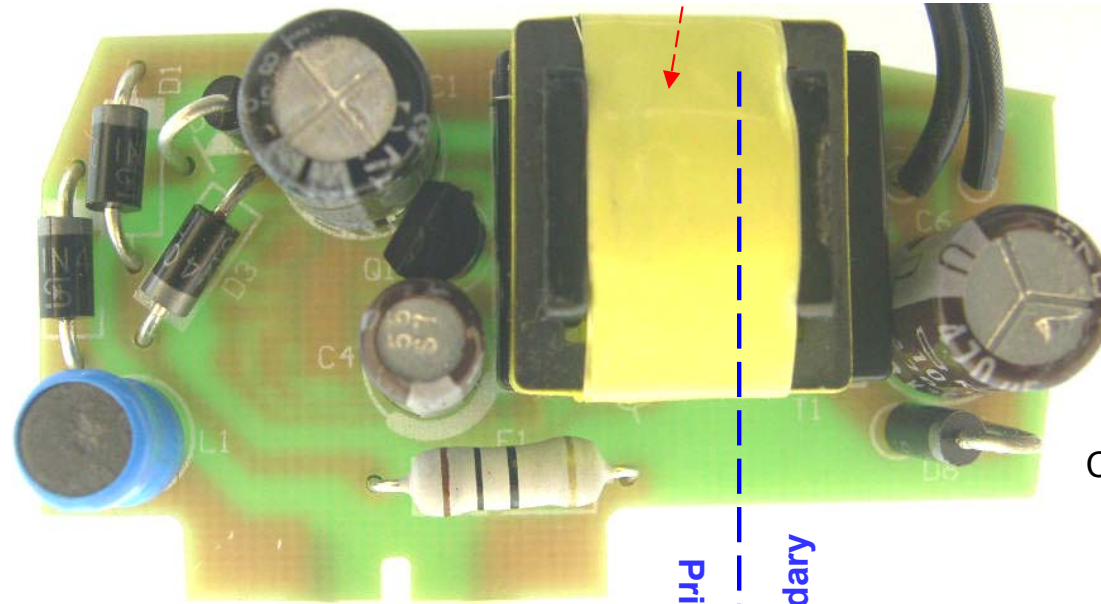
Smaller BJT can be selected because of lower operating frequency (45KHz) and lower  $I_{PRI}$  (<170mA).

Very tight output voltage regulation with option of cable drop compensation. (e.g. iW1690-02, 45KHz, @150mV compensated during full load)

Note: The parameter of blue items( ) was updated from 5V400mA design in order to adapt to 5V550mA design.

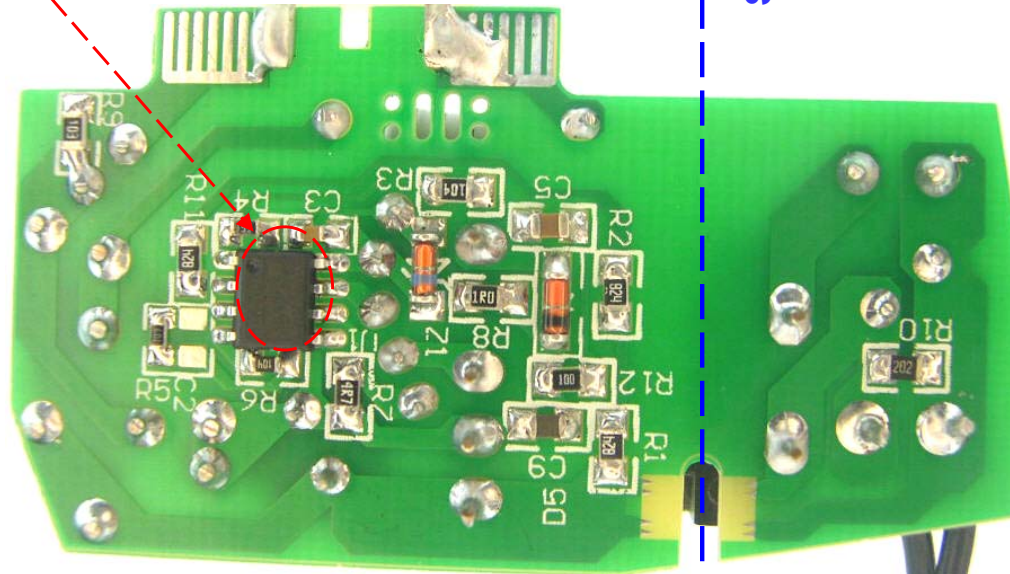
### 3. Circuit Board Photograph

Low Cost EE16 Transformer



Component side

Primary PWM Controller iW1690-02  
(45KHz, Cable Compensation:150mV)



Primary

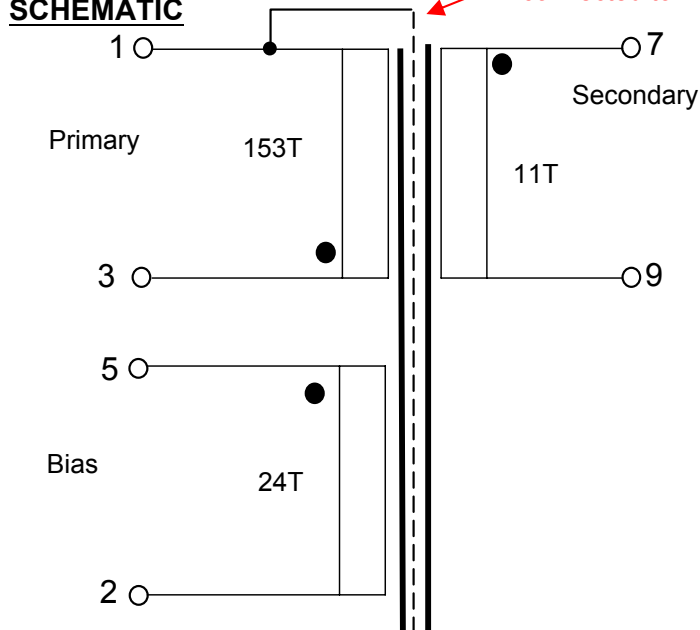
Secondary

Solder side

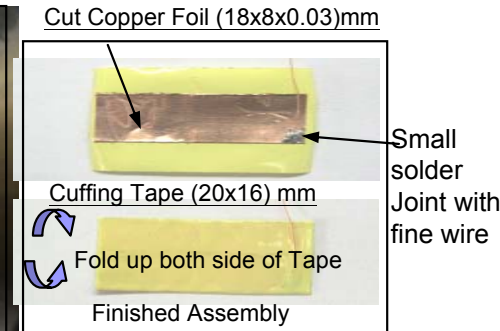
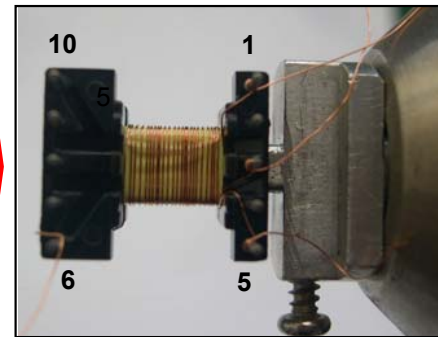


# 4. Transformer

## SCHEMATIC



Winding Start  
Pin-3 & End at  
Pin-1 in  
Clockwise  
direction  
looking from  
pin 6-10 side of  
the bobbin



## ELECTRICAL SPECIFICATIONS:

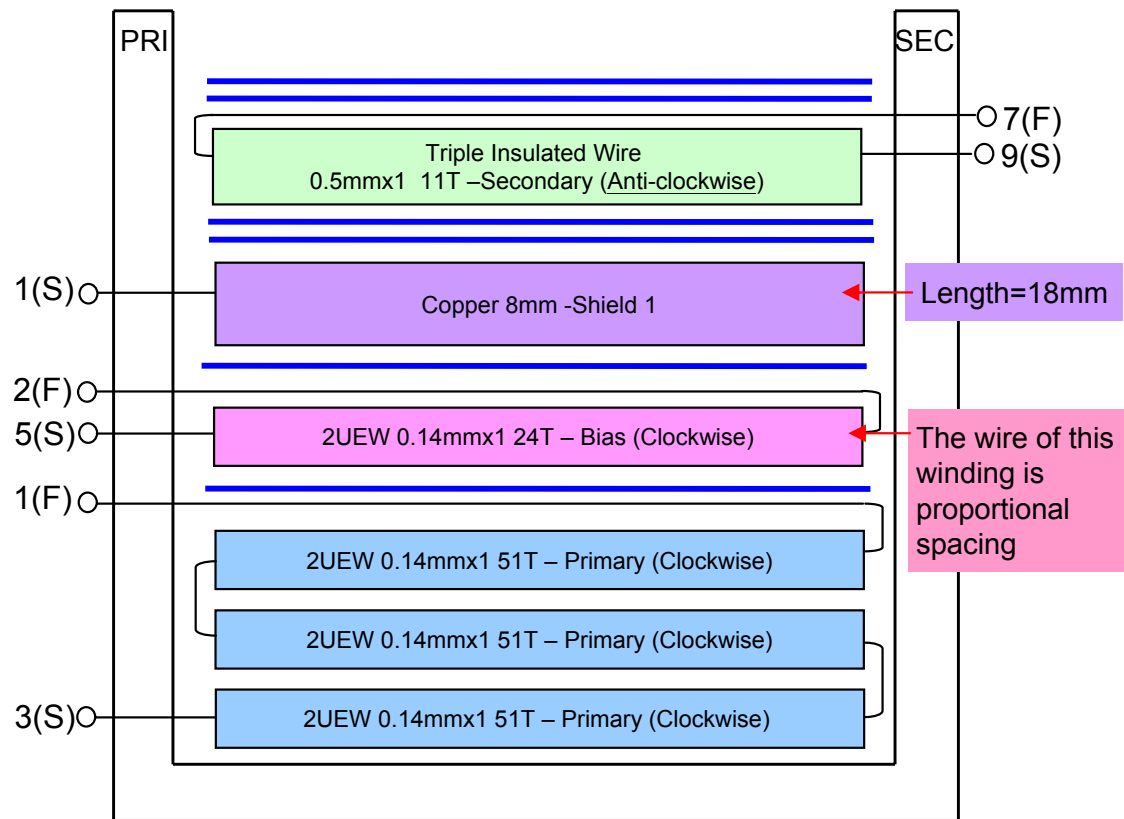
1. Primary Inductance ( $L_p$ ) = 3.3mH ( $\pm 10\%$ )@10KHz
2. Electrical Strength = 3KV, 50/60Hz, 1Min (pins 1~5 to pins 6~10)

## MATERIALS:

1. Core : EE16 (Ferrite Material TDK PC40 or equivalent)
2. Bobbin : EE16 Horizontal
3. Magnet Wires (Pri) : Type 2-UEW
4. Magnet Wire (Sec) : Triple Insulated Wires
5. Layer Insulation Tape : 3M1298 or equivalent.

## FINISHED :

1. Cut remained of Pin 4, 6, 8, pin 10 after wires termination
2. Varnish the complete assembly



## 5. Bill of Material

Item	Qty.	Ref.	Description	Cost (US Cent) / unit	Sub-Total (Cent)
1	1	U1	iW1690-02, Off-line digital PWM Controller, SO-8		
3	1	C1	4.7uF, 400V, E-CAP, (ESR<7Ω@10KHz and 25°C)		
2	1	C2	OPEN		
4	1	C3	100nF, 25V, X5R, SMD-0603		
5	1	C4	4.7uF, 50V, Low ESR E-CAP, 5x11.5		
6	1	C5	470pF, 100V, SMD-0805		
7	1	C6	470uF, 10V, Low ESR E-CAP		
6	1	C7	47nF, SMD-0603		
6	1	C9	47nF, SMD-0805		
8	2	D1,D3	FR107, Rectifier Diode, DO-41		
8	2	D2,D4	1N4007, Rectifier Diode, DO-41		
9	1	D5	FR102, Fast Rectifier Diode		
10	1	D6	SR160, Schottky Diode, DO-41		
11	1	F1	10Ω, Fuse Resistor, 0.5W		
12	1	L1	4.7mH, Filter Inductor		
13	1	Q1	STBV42, 700V/1A, HV Transistor, TO-92		
14	1	R9	10KΩ ±5 %, SMD-0805		
15	1	R7	3.9Ω ±1 %, SMD-0805		
16	1	R3	100KΩ ±1 %, SMD-0805		
17	1	R4	15.5KΩ ±1 %, SMD-0603		
18	1	R5	11KΩ ±1 %, SMD-0603		
19	1	R6	100KΩ ±1 %, SMD-0603		
20	3	R1,R2,R11	820KΩ ±1 %, SMD-0805		
21	1	R12	10Ω ±5 %, SMD-0805		
22	1	R8	1Ω ±5 %, SMD-0805		
23	1	R10	2KΩ ±5 %, SMD-0805		
24	1	T1	EE16, Transformer		
25	1	Z1	15V±2%, Zener diode, 0.5W		
26	1	PCB	Single Board, 94V0		

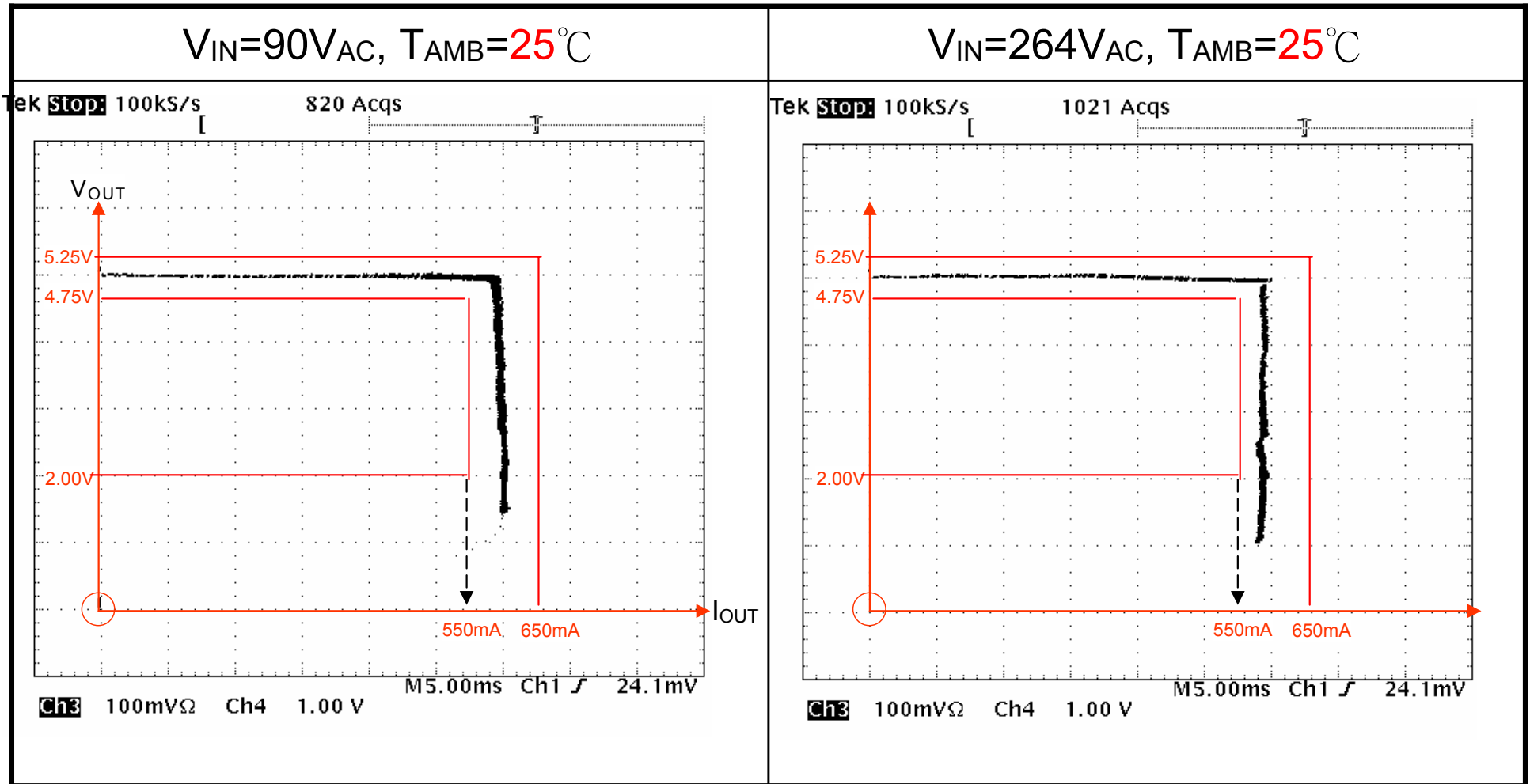
## 6. Regulation, Ripple and Efficiency Measurement

\* Note: Output voltage measured at end of PCB.

V <sub>IN</sub> (V <sub>AC</sub> )	P <sub>IN</sub> (W)	V <sub>OUT</sub> (V)	I <sub>OUT</sub> (mA)	V <sub>RIPPLE</sub> (mV <sub>P-P</sub> )	P <sub>OUT</sub> (W)	η (%)	OCP (mA)	P <sub>IN-S/C</sub> (mW)	Average η(%)	EPA 2.0 η (%)
90	0.06	5.10	0	7	/	/	607	52	73.0	Meet EPA2.0 With lot of margins !
	0.94	5.08	137	35	0.70	74.04				
	1.90	5.13	275	45	1.41	74.25				
	2.95	5.19	412	70	2.14	72.48				
	4.02	5.22	550	88	2.87	71.42				
115	0.07	5.09	0	7	/	/	609	58	73.9	63.7
	0.97	5.08	137	37	0.70	71.75				
	1.88	5.13	275	45	1.41	75.04				
	2.88	5.19	412	65	2.14	74.25				
	3.86	5.22	550	75	2.87	74.38				
230	0.12	5.10	0	7	/	/	592	104	70.3	63.7
	1.13	5.11	137	36	0.70	61.95				
	1.99	5.17	275	43	1.42	71.44				
	2.94	5.21	412	62	2.15	73.01				
	3.84	5.23	550	64	2.88	74.91				
264	0.14	5.12	0	7	/	/	590	122	68.2	63.7
	1.20	5.11	137	39	0.70	58.34				
	2.05	5.17	275	42	1.42	69.35				
	3.02	5.21	412	60	2.15	71.08				
	3.89	5.23	550	62	2.88	73.95				

# 7. Output VI Characteristics

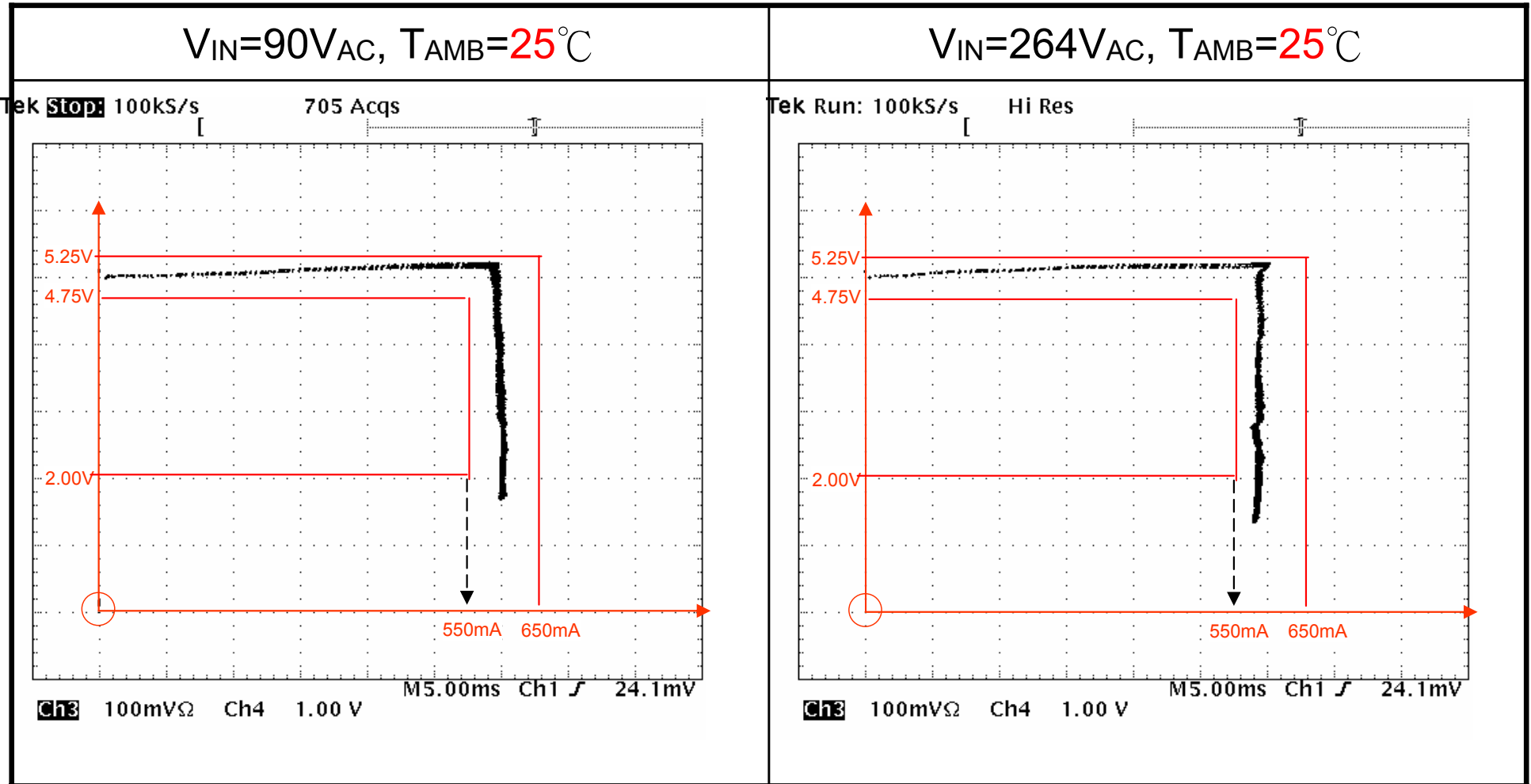
\* Note: Output voltage measured at DC-Cable(24AWG, 1.8m, 0.4 Ω ) terminal, T<sub>AMB</sub>=25 °C



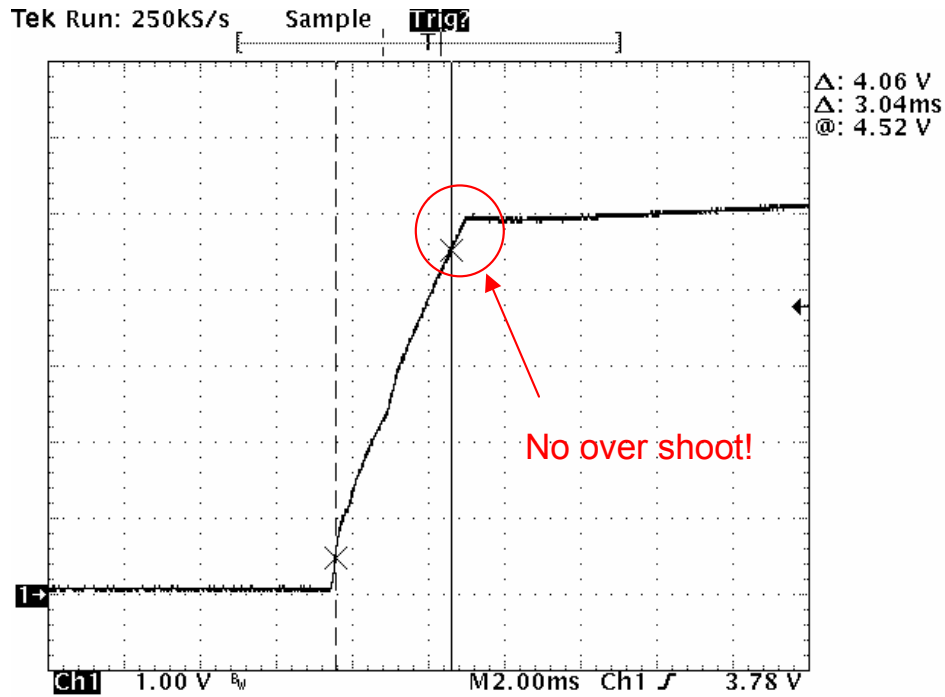


# 8. Output VI Characteristics

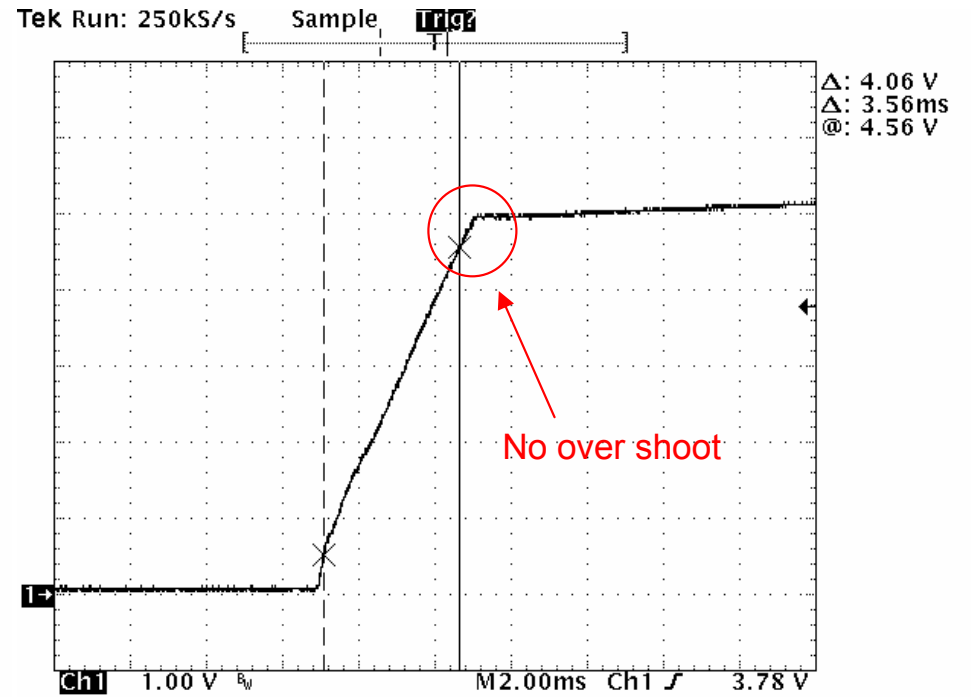
\* Note: Output voltage measured at the end of PCB,  $T_{AMB}=25^{\circ}\text{C}$



# 9. Output Voltage Rise Time

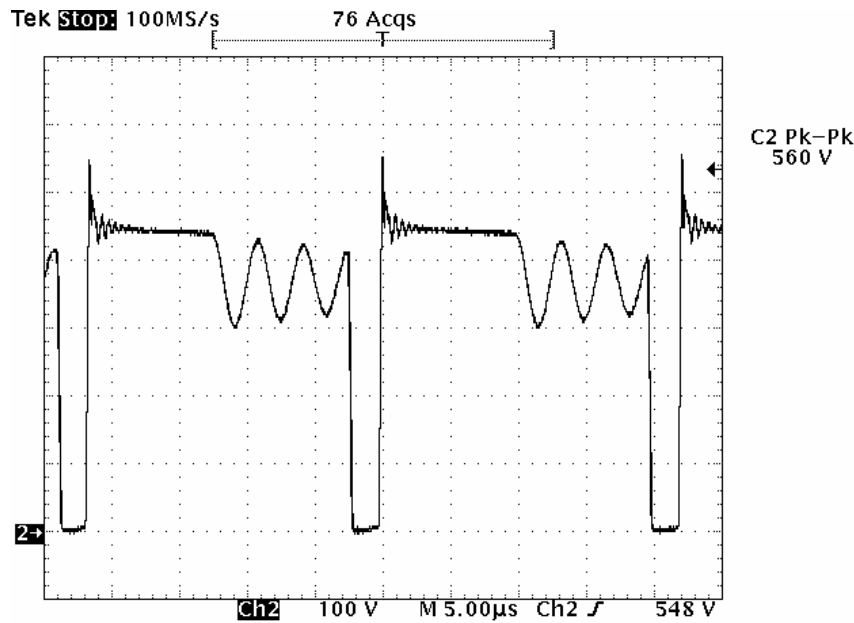


90VAC, No Load  
1V/Div, 2ms/Div



264VAC, No Load  
1V/Div, 2ms/Div

# 10. $V_{CE}$ waveform



Test Condition:

$V_{IN}=264V_{AC}$ ,  $I_{OUT\_CV}=550mA$

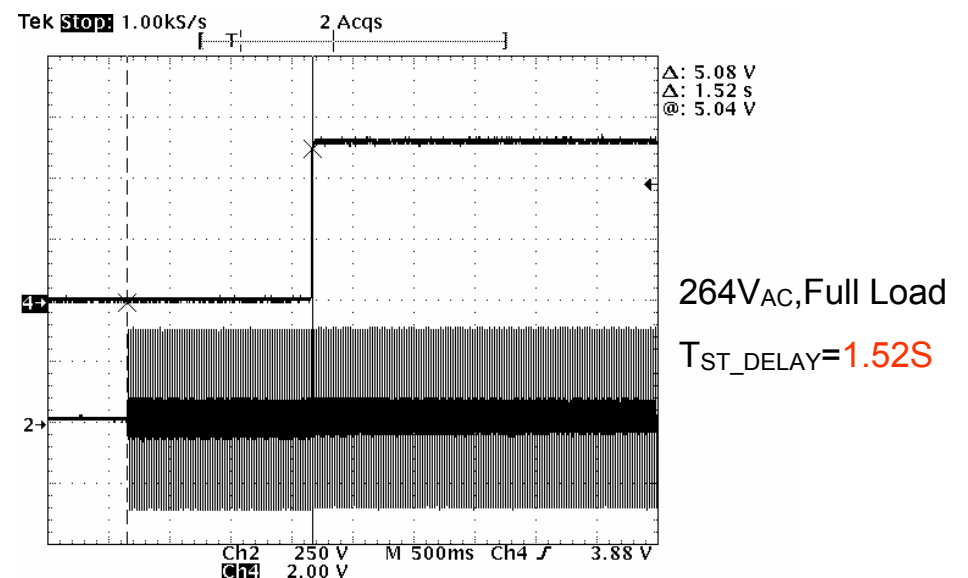
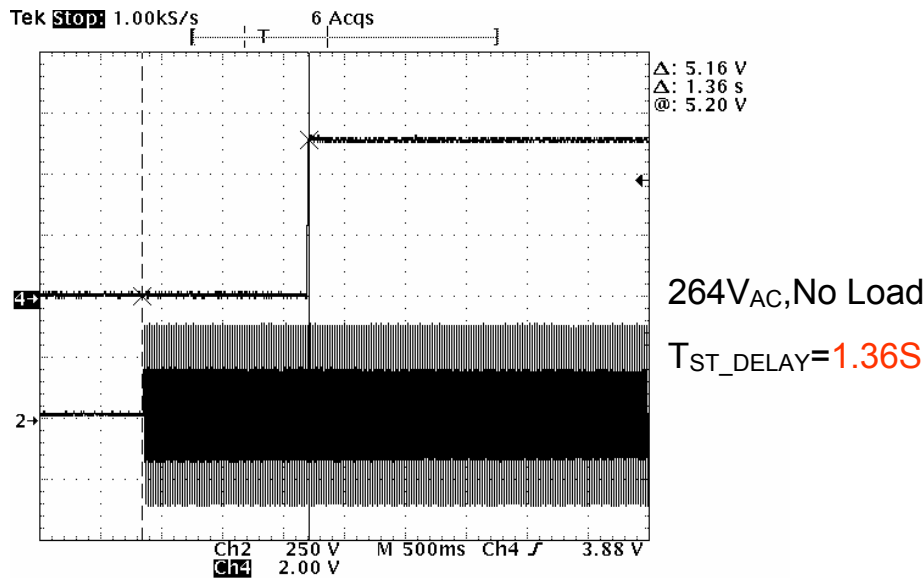
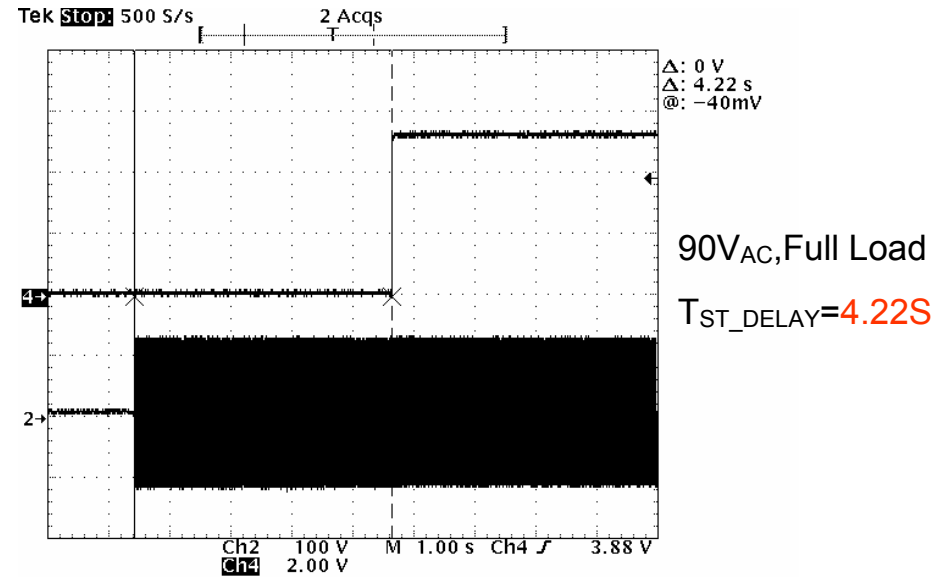
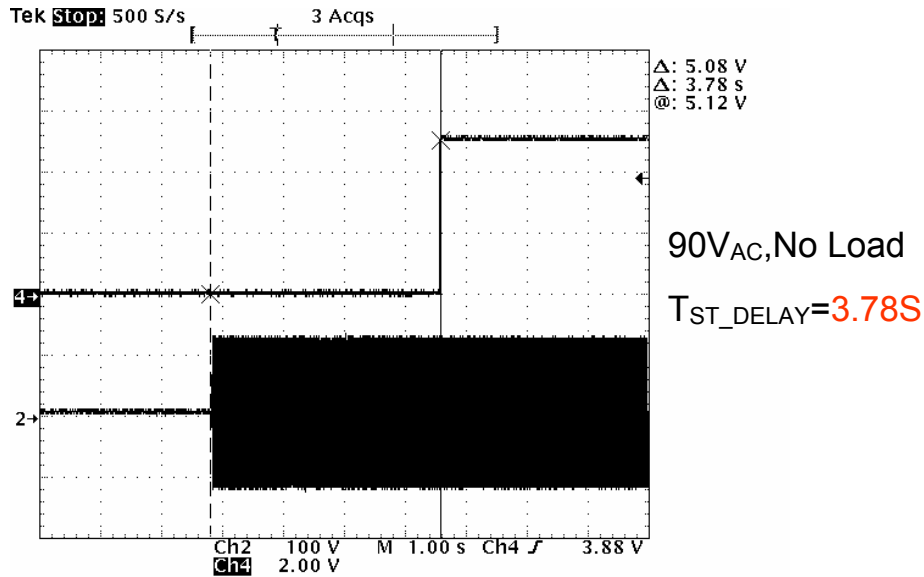
Result:

$V_{CE\_MAX}=\underline{560V}$

## Appendix – Simple Specification for used Transistor(STBV42)

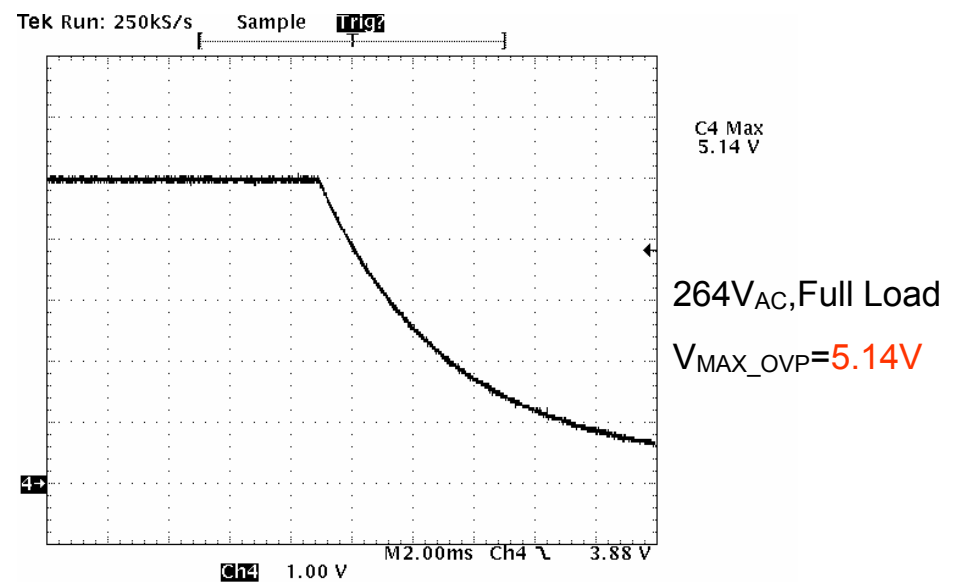
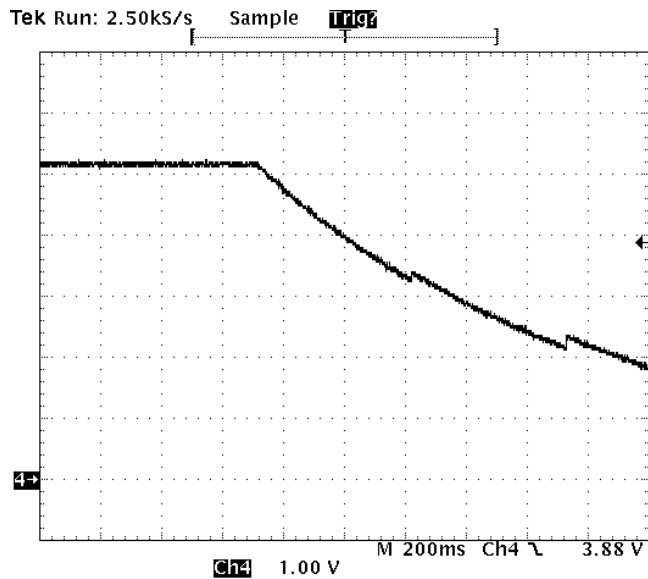
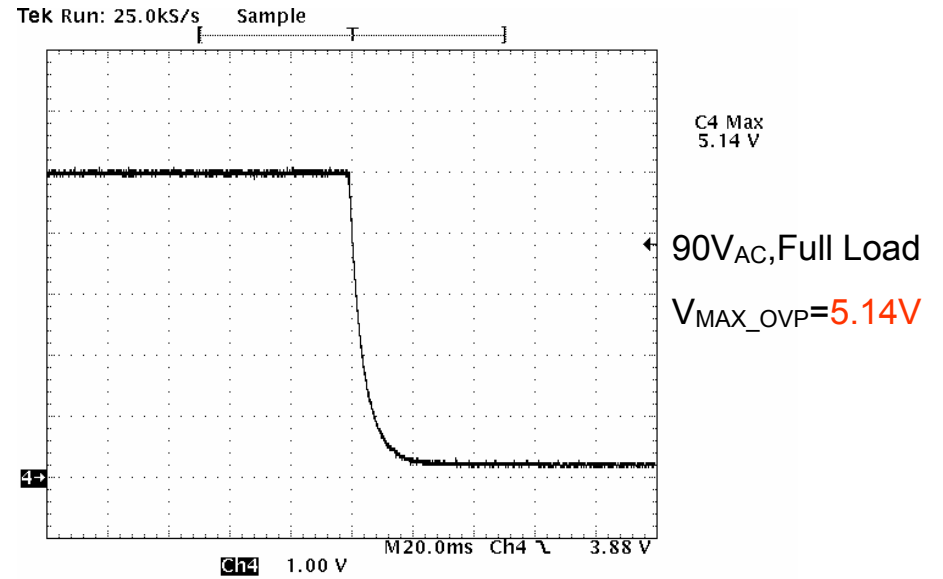
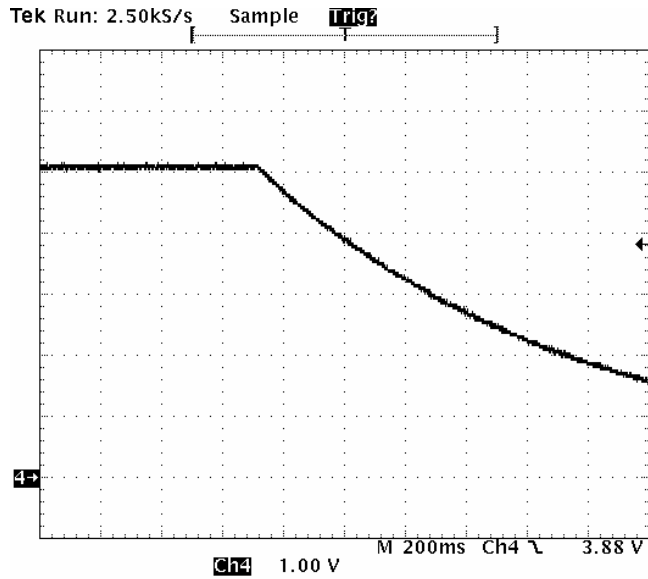
Symbol	Parameter	Value	Unit
$V_{CES}$	Collector-Emitter Voltage ( $V_{BE} = 0$ )	700	V
$V_{CEO}$	Collector-Emitter Voltage ( $I_B = 0$ )	400	V
$V_{EBO}$	Emitter-Base Voltage ( $I_C = 0$ )	9	V
$I_C$	Collector Current	1	A
$I_{CM}$	Collector Peak Current ( $t_p < 5$ ms)	2	A
$I_B$	Base Current	0.5	A
$I_{BM}$	Base Peak Current ( $t_p < 5$ ms)	1	A
$P_{tot}$	Total Dissipation at $T_{amb} = 25$ °C	1	W
$T_{stg}$	Storage Temperature	-65 to 150	°C
$T_j$	Max. Operating Junction Temperature	150	°C

# 11. Start Up & Turn On Delay Time



# 12. OVP Performance

-(R4 is shorted, or R3 is opened.)

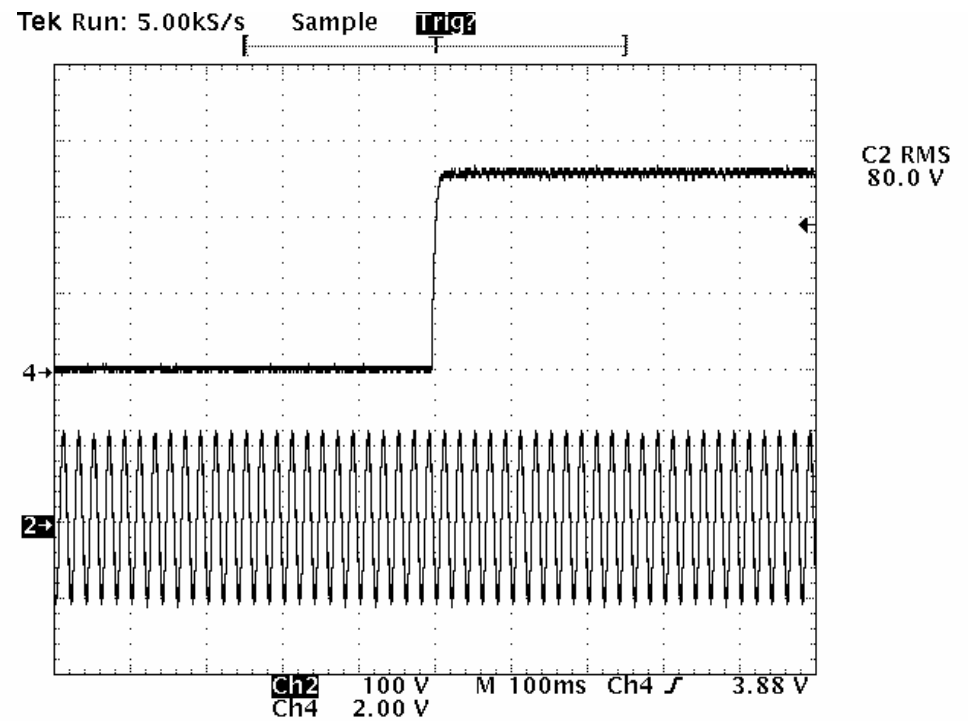
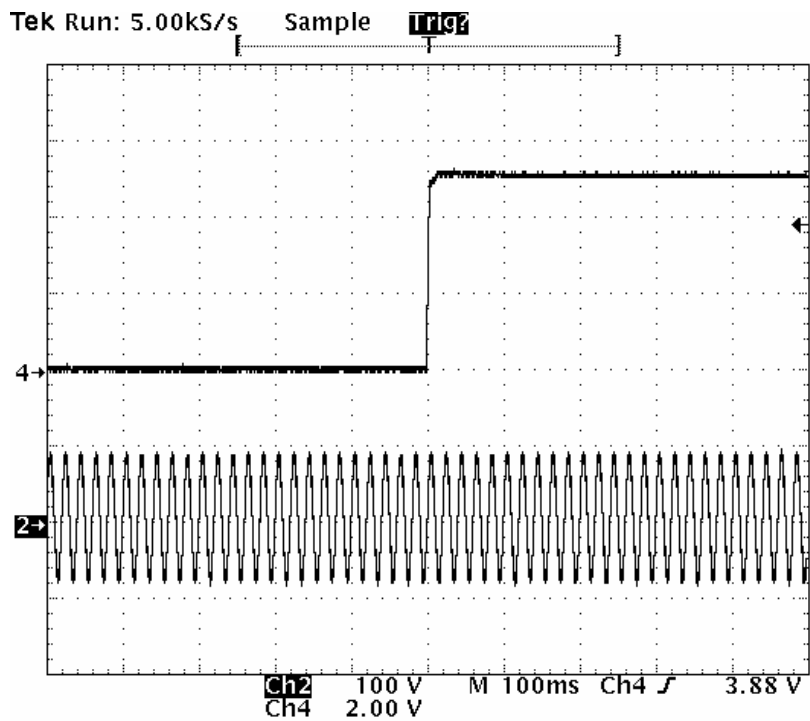


# 13. AC Startup Voltage Characteristic



No Load,  $V_{IN\_STARTUP} = 61.0V_{AC}$

Full Load,  $V_{IN\_STARTUP} = 80.0V_{AC}$

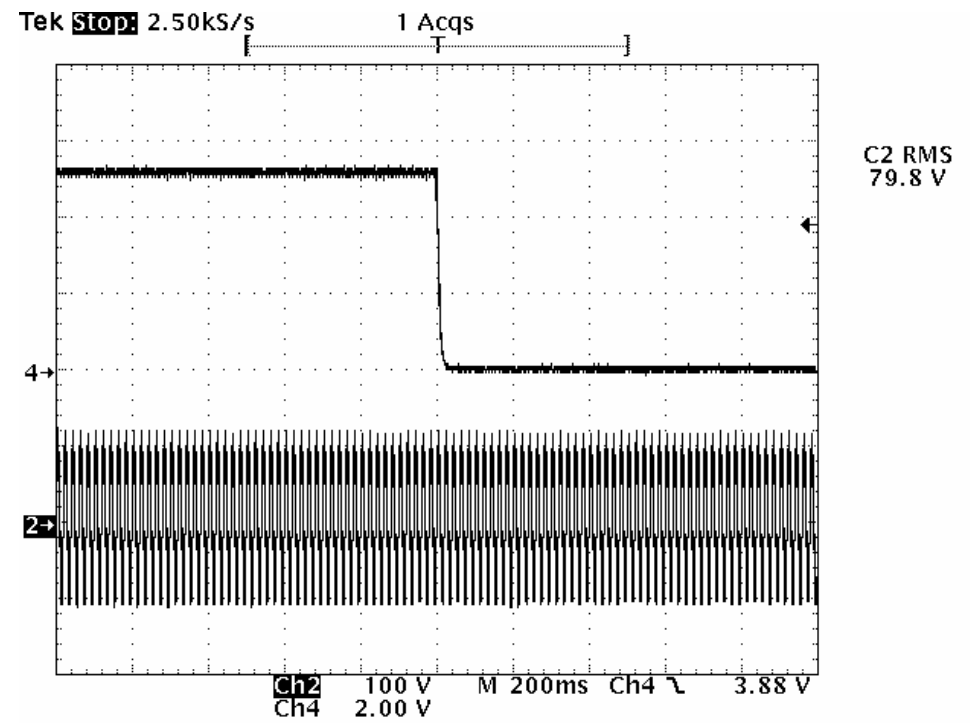
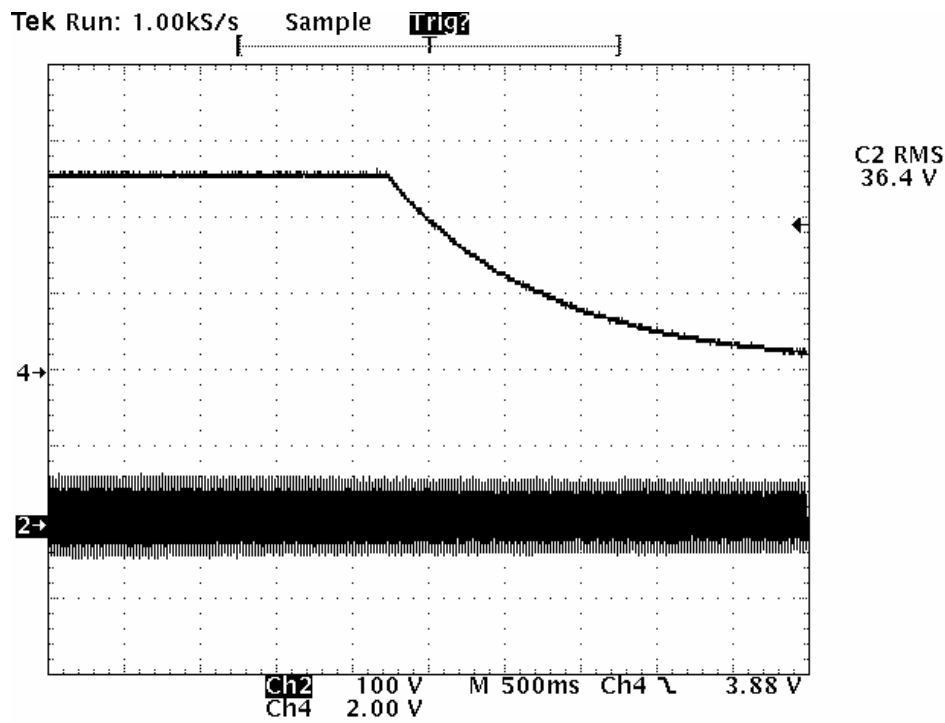


# 14. AC Brownout Voltage Characteristic



No Load,  $V_{IN\_BROWNOUT} = 36.4V_{AC}$

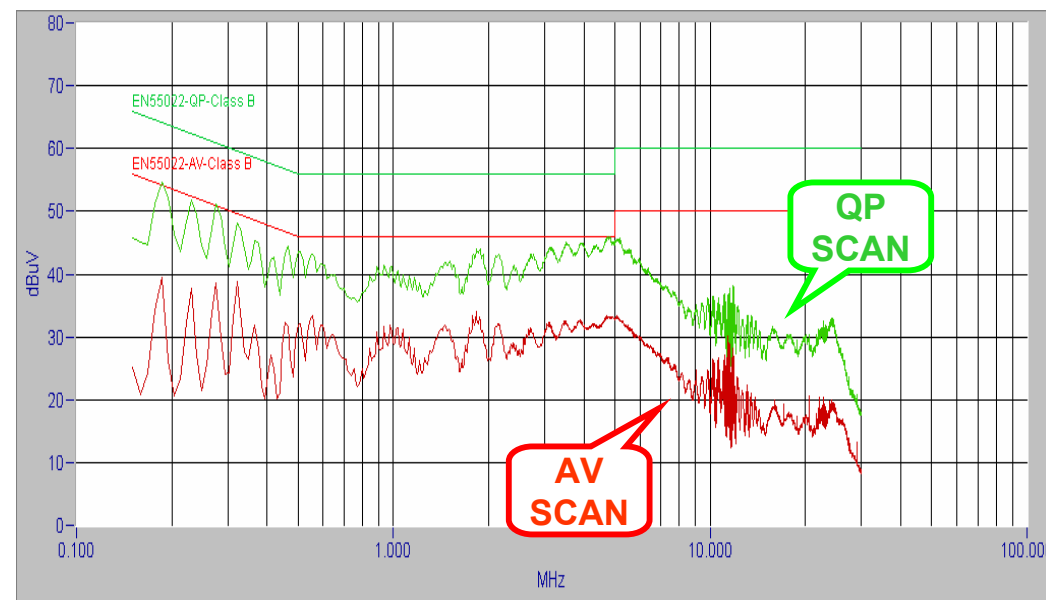
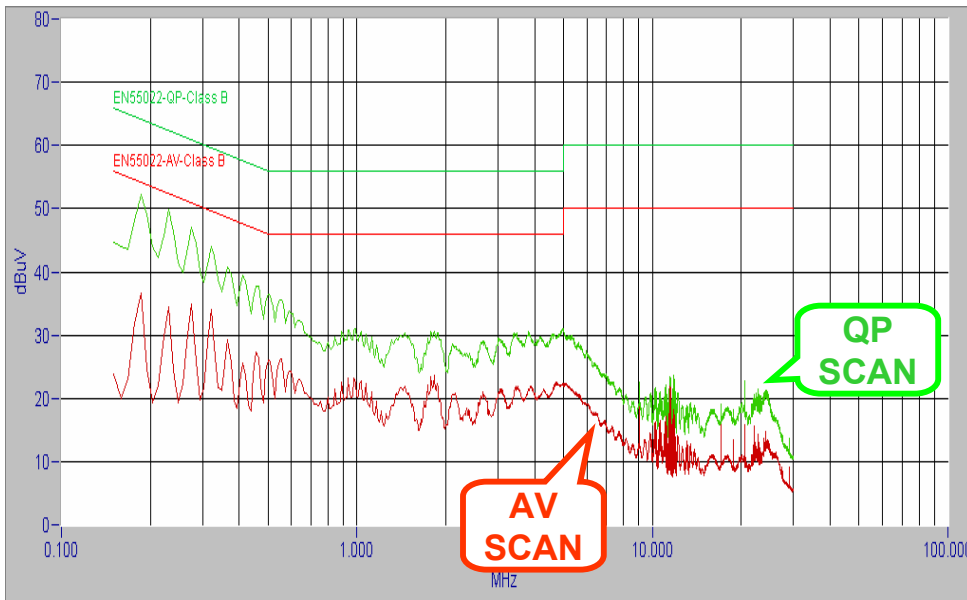
Full Load,  $V_{IN\_BROWNOUT} = 79.8V_{AC}$



# 15. Conducted EMI

230V<sub>AC</sub>/50Hz, Live

230V<sub>AC</sub>/50Hz, Neutral



Test Conditions : Resistive Full load. Output Ungrounded.